

Taiwan Semiconductor

PerF∃T[™]Power Transistor

FEATURES

- Ultra-low On-resistance
- Wettable Flank leads for Enhanced AOI
- 100% UIS and Rg tested
- 175°C Operating Junction Temperature
- RoHS Compliant
- Halogen-Free according to IEC 61249-2-21

| PRODUCT SUMMARY | | | | |
|---------------------------|----------------|----------------|----|--|
| PARAMETER | | ARAMETER VALUE | | |
| V_{DS} | | 40 | V | |
| R _{DS(on)} (max) | $V_{GS} = 10V$ | 1.9 | 0 | |
| | $V_{GS} = 7V$ | 2.3 | mΩ | |
| Q_{g} | $V_{GS} = 10V$ | 89 | nC | |



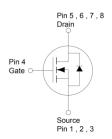




APPLICATIONS

- DC-DC Converters
- Solenoid and Motor Drivers
- Load Switch





Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted) | | | | |
|---|----------------------------------|-----------------|--------------|----|
| PARAMETER | SYMBOL | LIMIT | UNIT | |
| Drain-Source Voltage | | V_{DS} | 40 | V |
| Gate-Source Voltage | | V_{GS} | ±20 | V |
| Continuous Drain Current, Silicon limited | $T_C = 25^{\circ}C$ | I _D | 214 | Α |
| | $T_C = 25^{\circ}C$ | | 100 | |
| Continuous Drain Current (Note 1) | $T_C = 100$ °C | I _D | 100 | Α |
| | $T_A = 25$ °C | | 30 | |
| Pulsed Drain Current | | I_{DM} | 400 | А |
| Single Pulse Avalanche Current (Note 2) | | I _{AS} | 41.9 | А |
| Single Pulse Avalanche Energy (Note 2) | | E _{AS} | 262.9 | mJ |
| Total Power Dissipation | T _C = 25°C | P _D | 150 | W |
| | $T_{\rm C} = 125^{\circ}{\rm C}$ | | 50 | VV |
| Operating Junction and Storage Temperature Range | | T_J,T_STG | - 55 to +175 | °C |

| THERMAL RESISTANCE | | | | |
|--|-----------------|---------|------|--|
| PARAMETER | SYMBOL | MAXIMUM | UNIT | |
| Thermal Resistance – Junction to Case | $R_{\Theta JC}$ | 1 | °C/W | |
| Thermal Resistance – Junction to Ambient | $R_{\Theta JA}$ | 50 | °C/W | |

Note: $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. $R_{\Theta JC}$ is guaranteed by design while $R_{\Theta CA}$ is determined by the user's board design.

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| PARAMETER | CONDITIONS | SYMBOL | MIN | TYP | MAX | UNIT |
|-----------------------------------|--|--------------------|-----|-------|------|------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V$, $I_D = 1mA$ | BV _{DSS} | 40 | | | V |
| Gate Threshold Voltage | $V_{GS} = V_{DS}, I_{D} = 250 \mu A$ | $V_{GS(TH)}$ | 2.4 | 3 | 3.6 | V |
| Gate-Source Leakage Current | $V_{GS} = \pm 20V, V_{DS} = 0V$ | I _{GSS} | | | ±100 | nA |
| | $V_{GS} = 0V, V_{DS} = 40V$ | I _{DSS} | | | 1 | |
| Drain-Source Leakage Current | $V_{GS} = 0V, V_{DS} = 40V$ $T_{J} = 125^{\circ}C$ | | | 100 | μA | |
| Drain-Source On-State Resistance | $V_{GS} = 10V, I_D = 50A$ | Б | | 1.3 | 1.9 | mΩ |
| (Note 3) | $V_{GS} = 7V, I_{D} = 50A$ | $R_{DS(on)}$ | | 1.6 | 2.3 | |
| Forward Transconductance (Note 3) | $V_{DS} = 10V, I_{D} = 25A$ | g _{fs} | | 133.6 | | S |
| Dynamic | | | | | | |
| Total Gate Charge | $V_{GS} = 7V, V_{DS} = 25V,$ $I_{D} = 30A$ | Q_g | | 64 | | |
| Total Gate Charge | | Q_g | | 89 | | nC |
| Gate-Source Charge | $V_{GS} = 10V, V_{DS} = 25V,$ | Q_{gs} | | 28 | | |
| Gate-Drain Charge | $I_D = 30A$ | Q_{gd} | | 16 | | |
| Input Capacitance | $V_{GS} = 0V, V_{DS} = 25V,$ | C _{iss} | | 6029 | | |
| Output Capacitance | | C _{oss} | | 1218 | | pF |
| Reverse Transfer Capacitance | f = 1.0MHz | C_{rss} | - | 47 | | |
| Gate Resistance | f = 1.0MHz | R_g | | 1.0 | | Ω |
| Switching (Note 4) | | | | | | |
| Turn-On Delay Time | $V_{GS} = 10V, V_{DS} = 25V,$ $I_{D} = 30A, R_{G} = 3.3\Omega$ | t _{d(on)} | - 1 | 23 | | |
| Rise Time | | t _r | | 76 | | |
| Turn-Off Delay Time | | $t_{d(off)}$ | | 52 | | nS |
| Fall Time | | t _f | | 18 | | |
| Source-Drain Diode | | | | | | |
| Diode Forward Voltage (Note 3) | $V_{GS} = 0V, I_{S} = 50A$ | V _{SD} | | | 1.1 | V |
| Reverse Recovery Time | I _S = 30A, | t _{rr} | | 61 | | nS |
| Reverse Recovery Charge | di/dt = 100A/µs | Q _{rr} | | 98 | | nC |

Notes:

- 1. Package current limit.
- 2. L = 0.3 mH, $V_{GS} = 10 V$, $R_G = 25 \Omega$, Starting $T_J = 25 ^{\circ} C$.
- 3. Pulse test: Pulse Width $\leq 300 \mu s$, duty cycle $\leq 2\%$.
- 4. Switching time is essentially independent of operating temperature.

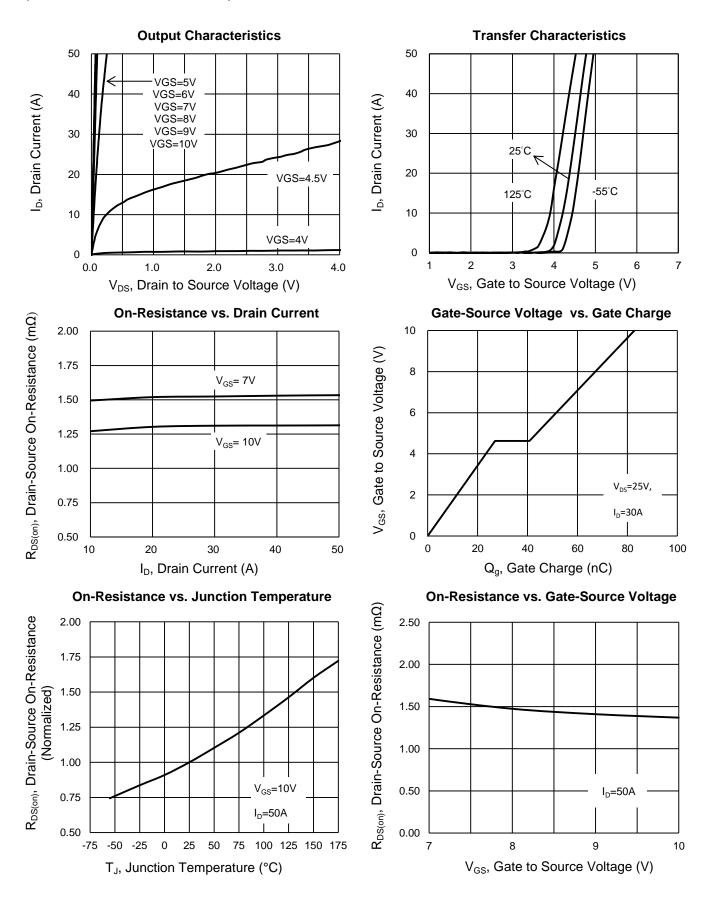
ORDERING INFORMATION

| ORDERING CODE | PACKAGE | PACKING |
|------------------|---------|---------------------|
| TSM019NH04CR RLG | PDFN56U | 2,500pcs / 13" Reel |



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

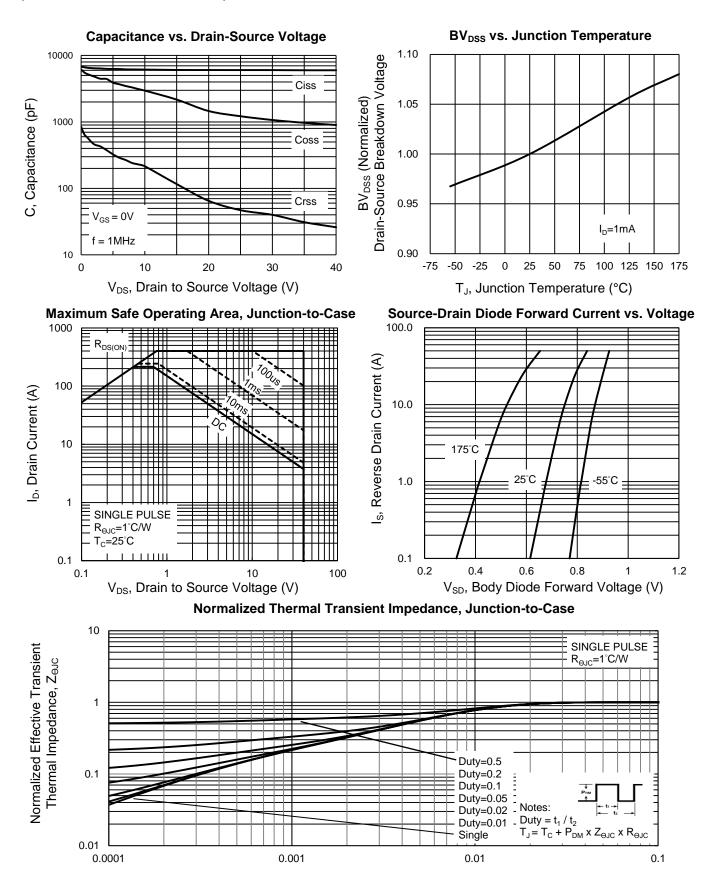


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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



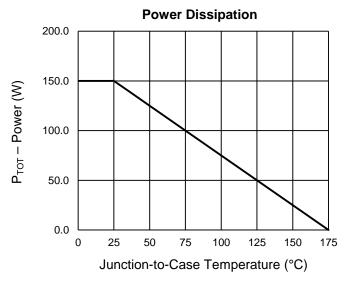
t, Square Wave Pulse Duration (sec)

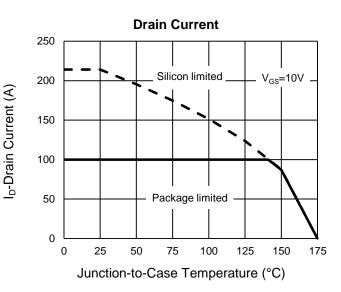




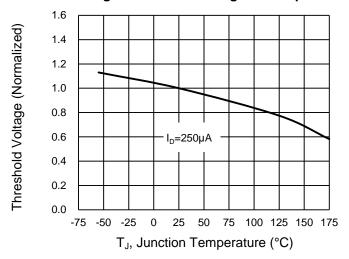
CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$





Normalized gate threshold voltage vs Temperature



Version: E2207

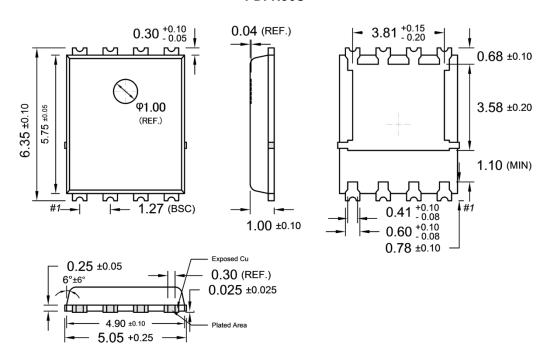
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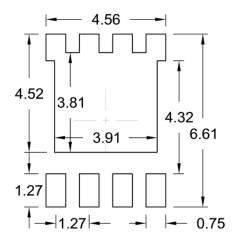


PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN56U



SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

WW = Week Code (01~52)

 $\mathbf{L} = \text{Lot Code } (1 \sim 9, A \sim Z)$

F = Factory Code



Taiwan Semiconductor

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